



深圳市三瑞思电子科技有限公司

Shenzhen Sunrise Electronic Technology Co., Ltd.

20SQ045

**20Amp SCHOTTKY BARRIER
RECTIFIERS**

Features

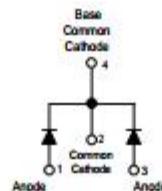
- Designed as Bypass Diodes for Solar Panels
- Selectively Rated for 200°C Maximum Junction Temperature for High Thermal Reliability
- Patented Super Barrier Rectifier Technology
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability



TO-263

Mechanical Data

- Case: TO-263
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 2026
- Weight: 2.24 grams (approximate)



Maximum Ratings @TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V RRM		
Working Peak Reverse Voltage	V RWM	45	V
DC Blocking Voltage	V RM		
RMS Reverse Voltage	V R(RMS)	32	V
Average Rectified Output Current	Io	15	A
Non-Repetitive Peak Forward Surge Current 8.3ms	IFSM	400	A
Single Half Sine-Wave Superimposed on Rated Load			

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance	R _{θJA}	2.5	°C/W
Thermal Resistance Junction to Ambient (Note 1)			
Operating Temperature Range	T _J	-55 to +200	°C
Storage Temperature Range	T _{STG}	-55 to +175	°C



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Electrical Characteristics

@ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop (Per Leg)	VF	-	-	0.60 0.55	V	IF = 20A, $T_J = 25^\circ\text{C}$ IF = 15A, $T_J = 125^\circ\text{C}$
Leakage Current (Note 2)	IR	-	-	0.3 100	mA	$V_R = 45\text{V}$, $T_J = 25^\circ\text{C}$ $V_R = 45\text{V}$, $T_J = 125^\circ\text{C}$

Notes: 1. Polymide, 2oz. Copper 16x minimum recommended pad layout |
2. Short duration pulse test used to minimize self-heating effect.

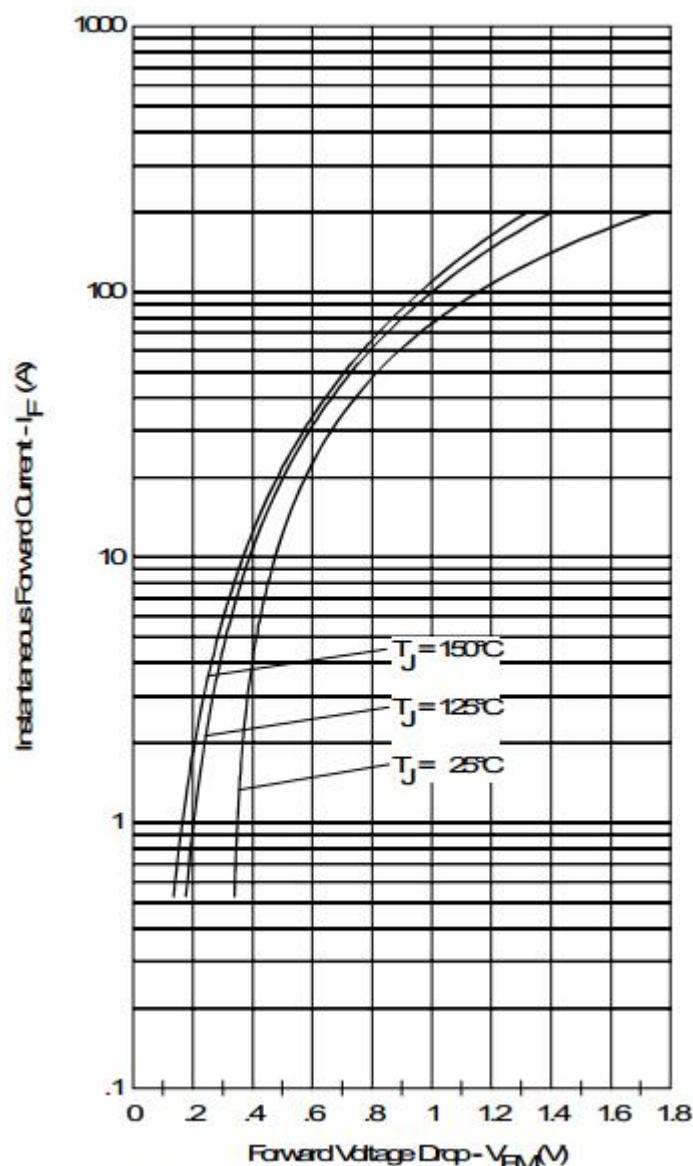


Fig. 1 - Maximum Forward Voltage Drop Characteristics

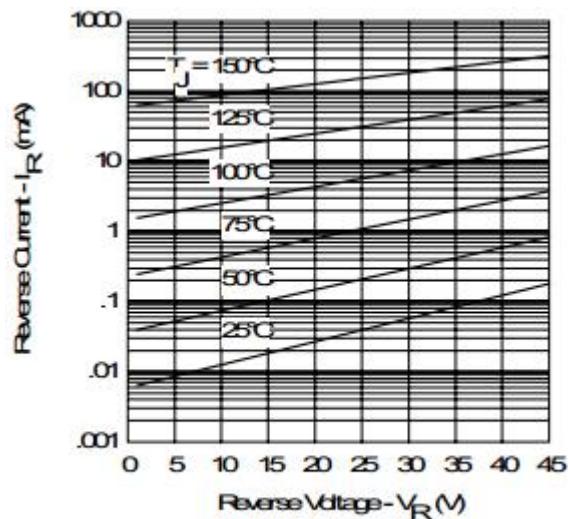


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

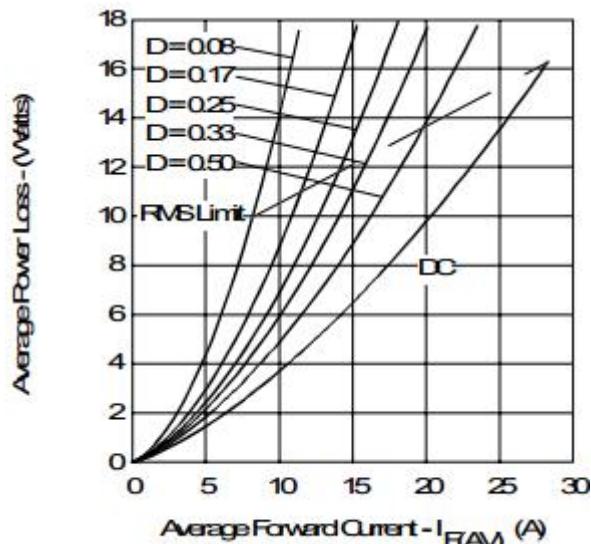


Fig. 6 - Forward Power Loss Characteristics



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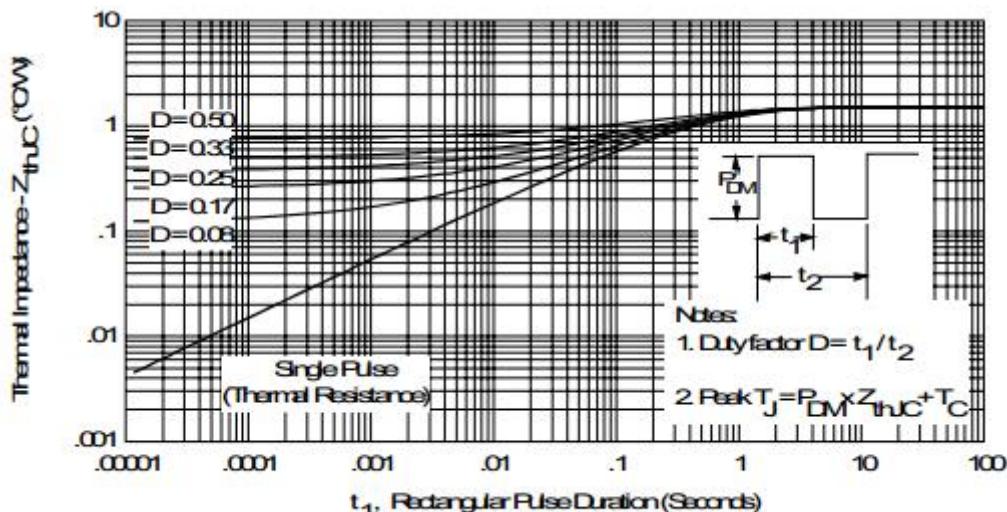
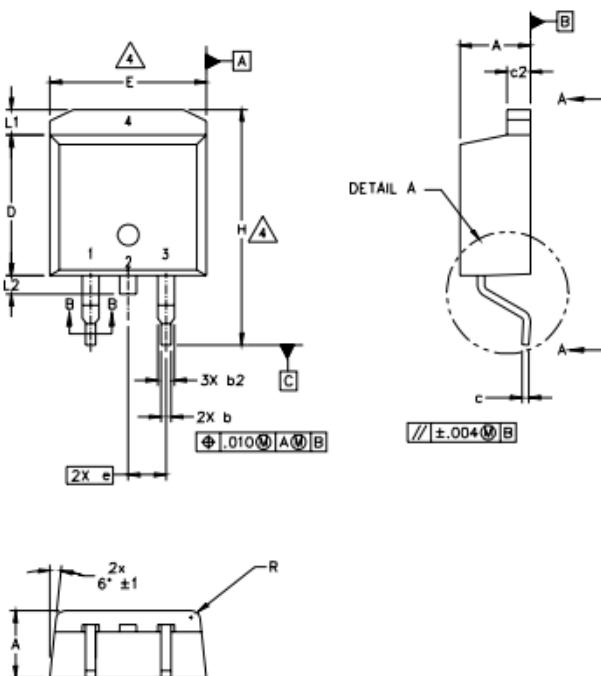


Fig. 4 - Maximum Thermal Impedance $Z_{th,JC}$ Characteristics

Package Outline Dimensions



SYMBOL	DIMENSIONS				NOTES	
	MILLIMETERS		INCHES			
	MIN.	MAX.	MIN.	MAX.		
A	4.06	4.83	.160	.190		
A1	0.00	0.254	.000	.010		
b	0.51	0.99	.020	.039		
b1	0.51	0.89	.020	.035	4	
b2	1.14	1.78	.045	.070		
c	0.38	0.74	.015	.029		
c1	0.38	0.58	.015	.023	4	
c2	1.14	1.65	.045	.065		
D	8.51	9.65	.335	.380	3	
D1	6.86		.270			
E	9.65	10.67	.380	.420	3	
E1	6.22		.245			
e	2.54	BSC	.100	BSC		
H	14.61	15.88	.575	.625		
L	1.78	2.79	.070	.110		
L1		1.65		.065		
L2	1.27	1.78	.050	.070		
L3	0.25	BSC	.010	BSC		
L4	4.78	5.28	.188	.208		
m	17.78		.700			
m1	8.89		.350			
n	11.43		.450			
o	2.08		.082			
p	3.81		.150			
R	0.51	0.71	.020	.028		
S	90°	93°	90°	93°		

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
4. DIMENSION b1 AND c1 APPLY TO BASE METAL ONLY.
5. CONTROLLING DIMENSION: INCH.